



60V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)}	Ι _D T _A = +25°C
-60V	150mΩ @ V _{GS} = -10V	-3A
-00 V	185mΩ @ V _{GS} = -4.5V	-2.7A

Description

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- Transformer Driving Switch
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) test in production
- Low on-resistance
- Fast switching speed
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

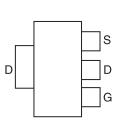
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See diagram below
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (approximate)

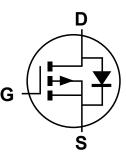


SOT223

Top View



Pin Out - Top View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
DMP6185SE-13	Standard	SOT223	2,500 / Tape & Reel

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

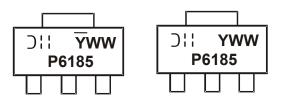
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:





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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source voltage		V _{DSS}	-60	V
Gate-Source voltage		V _{GS}	±20	V
	T _A = +25°C		-3	•
Continuous Drain current (Note 6) V_{GS} = -10V	T _A = +70°C	ID	-2.4	A
Maximum Body Diode Continuous Current		Is	-2	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)		I _{DM}	-15	A
Single Pulsed Avalanche Current (Note 7)		I _{AS}	-16	A
Single Pulsed Avalanche Energy (Note 7)		E _{AS}	13	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Tatal Dawar Dissination (Note 5)	T _A = +25°C	D	1.2	W
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.8	
Thermal Resistance Junction to Ambient (Note E)	Steady state	D	104	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	51	
Total Dower Dissinction (Note 6)	T _A = +25°C	P	2.2	w
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.4	
Thermal Desistance Junction to Ambient (Note 6)	Steady state	D	60	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R _{0JA}	30	
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	7.6		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	-						
Drain-Source Breakdown Voltage	BV _{DSS}	-60	-	-	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	-	-	-1	μA	V _{DS} = -48V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	-1	-	-3	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Deserver		110	150	mΩ	V _{GS} = -10V, I _D = -2.2A	
Static Drain-Source On-Resistance	R _{DS} (ON)	-	130	185	11122	V _{GS} = -4.5V, I _D = -1.8A	
Diode Forward Voltage	V _{SD}	-	-0.75	-0.95	V	V _{GS} = 0V, I _S = -1A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	-	708	-	pF		
Output Capacitance	C _{oss}	-	39	-	pF	= V _{DS} = -30V, V _{GS} = 0V, - f = 1MHz	
Reverse Transfer Capacitance	Crss	-	32	-	pF		
Gate Resistance	Rg	-	17	28	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} = -4.5V)	Qg	-	6.2	-	nC		
Total Gate Charge (V _{GS} = -10V)	Qg	-	14	-	nC	V _{DS} = -30V. I _D = -12A	
Gate-Source Charge	Q _{gs}	-	2.8	-	nC	$V_{\rm DS} = -30V, I_{\rm D} = -12A$	
Gate-Drain Charge	Q _{gd}	-	3.1	-	nC	7	
Turn-On Delay Time	t _{D(on)}	-	5.2	-	ns		
Turn-On Rise Time	tr	-	23	-	ns	V_{DS} = -30V, R _L = 2.5 Ω V_{GS} = -10V, R _G = 3 Ω	
Turn-Off Delay Time	t _{D(off)}	-	33	-	ns		
Turn-Off Fall Time	t _f	-	39	-	ns		
Body Diode Reverse Recovery Time	trr	-	22	-	ns		
Body Diode Reverse Recovery Charge	Qrr	-	17	-	nC	—I _F = -12A, di/dt = 100A/μs	

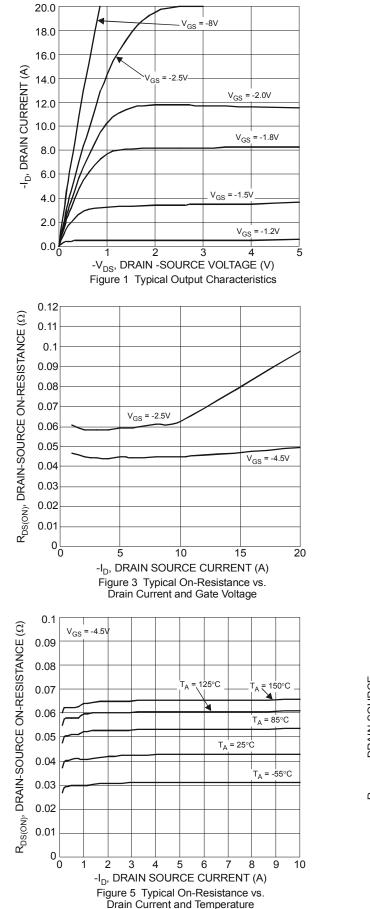
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. 7. UIS in production with L = 0.1mH, starting $T_A = +25^{\circ}C$.

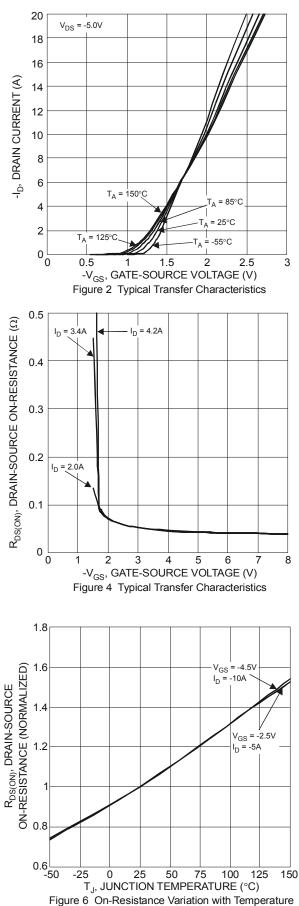
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

Notes:



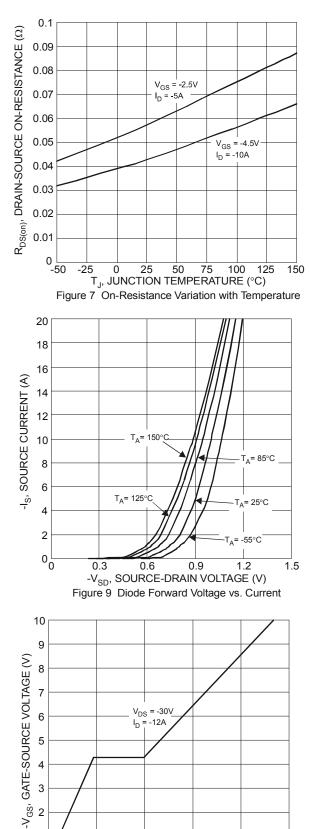
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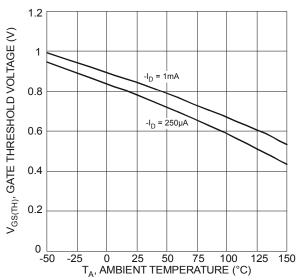




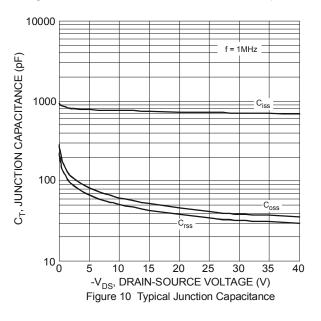


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Q_q, TOTAL GATE CHARGE (nC) Figure 11 Gate-Charge Characteristics

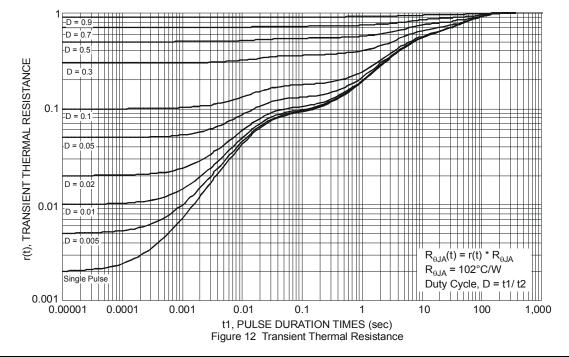
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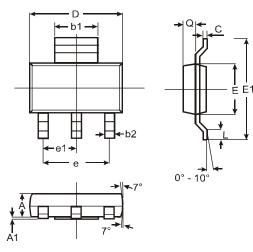
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Package Outline Dimensions

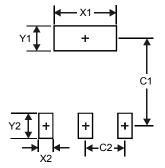
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
ш	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е			4.60		
e1		_	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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